

ABSTRACT OF THE DISCLOSURE

A semiconductor laser for emitting evanescent light that has a laser beam-emitting end facet including a light-emitting region is constituted to comprise a three-dimensional feature portion formed on the laser beam-emitting end facet, a light-shielding film covering at least the light-emitting region, and a small opening for emitting the evanescent light formed in the light-shielding film at a location to have a prescribed positional relationship with the three-dimensional feature portion. The presence of the three-dimensional feature portion enables the small opening to be formed precisely with respect to the light-emitting region by a simple operation.

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